

Specifications	
Part Number	RN2111ACT(TPL3)
Manufacturer	Touchstone Semiconductor
Description	TRANS PREBIAS PNP 0.1W CST3
Category	Discrete Semiconductor Products > Transistors - Bipolar
Part Status	2664 pcs Stock
Voltage - Collector Emitter Breakdown (Max)	80mA
Voltage - Breakdown	CST3
Vce Saturation (Max) @ Ib, Ic	50V
Series	-
RoHS Status	Tape & Reel (TR)
Resistor - Emitter Base (R2) (Ohms)	10k
Resistor - Base (R1) (Ohms)	-
Power - Max	100mW
Polarization	SC-101, SOT-883
Other Names	RN2111ACT(TPL3)TR
Noise Figure (dB Typ @ f)	-
Mounting Type	Surface Mount
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Manufacturer Part Number	RN2111ACT(TPL3)
Frequency - Transition	120 @ 1mA, 5V
Expanded Description	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased 50V
Description	TRANS PREBIAS PNP 0.1W CST3
DC Current Gain (hFE) (Min) @ Ic, Vce	100nA (ICBO)
Current - Collector Cutoff (Max)	150mV @ 250µA, 5mA
Current - Collector (Ic) (Max)	PNP - Pre-Biased

You May Be Also Be interested

In:  RN2111FV TOSHIBA TOSHIBA SOT523	 RN2111,LF(CB) Toshiba Semiconductor and Storage TRANS PREBIAS PNP 50V 0.1W SSM	 RN2111MFV TOSHIBA RN2111MFV TOSHIBA	 RN2111ACT(TPL3) Toshiba Semiconductor and Storage TRANS PREBIAS PNP 0.1W CST3
 RN2111F TOSHIBA RN2111F TOSHIBA	 RN2111ACT TOSHIBA TOSHIBA CST3	 RN2111 TOSHIBA RN2111 TOSHIBA	 RN2111CT(TPL3) Toshiba Semiconductor and Storage TRANS PREBIAS PNP 0.05W CST3

RN2111ACT(TPL3) Related keyword [More](#)

RN2111ACT(TPL3) Touchstone Semiconductor	RN2111ACT(TPL3) Data Sheet	RN2111ACT(TPL3) Datasheets	RN2111ACT(TPL3) PDF	Touchstone Semiconductor RN2111ACT(TPL3)
RN2111ACT(TPL3) Electronic	RN2111ACT(TPL3) Components	RN2111ACT(TPL3) Distributor	RN2111ACT(TPL3) Image	RN2111ACT(TPL3) Part
RN2111ACT(TPL3) Price	RN2111ACT(TPL3) Manufacturer	RN2111ACT(TPL3) Picture	RN2111ACT(TPL3) Stock	RN2111ACT(TPL3) Inventory
RN2111ACT(TPL3) New	RN2111ACT(TPL3) Original	RN2111ACT(TPL3) Warranted	RN2111ACT(TPL3) RFQ	RN2111ACT(TPL3) Order Online